

Welcome to [E-XFL.COM](https://www.e-xfl.com)

What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

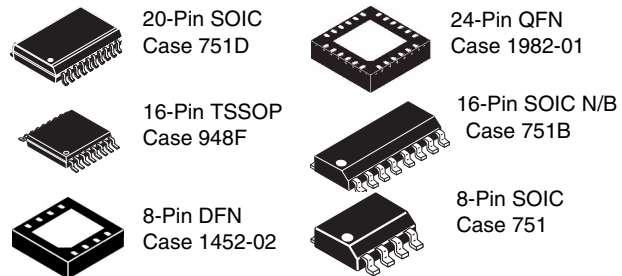
| | |
|----------------------------|---|
| Product Status | Active |
| Core Processor | RS08 |
| Core Size | 8-Bit |
| Speed | 20MHz |
| Connectivity | I ² C, SPI |
| Peripherals | LVD, POR, PWM, WDT |
| Number of I/O | 6 |
| Program Memory Size | 2KB (2K x 8) |
| Program Memory Type | FLASH |
| EEPROM Size | - |
| RAM Size | 126 x 8 |
| Voltage - Supply (Vcc/Vdd) | 1.8V ~ 5.5V |
| Data Converters | A/D 4x10b |
| Oscillator Type | Internal |
| Operating Temperature | -40°C ~ 85°C (TA) |
| Mounting Type | Surface Mount |
| Package / Case | 8-SOIC (0.154", 3.90mm Width) |
| Supplier Device Package | 8-SOIC |
| Purchase URL | https://www.e-xfl.com/product-detail/nxp-semiconductors/mc9rs08kb2csc |



MC9RS08KB12

MC9RS08KB12 Series

Covers: MC9RS08KB12
MC9RS08KB8
MC9RS08KB4
MC9RS08KB2



- 8-Bit RS08 Central Processor Unit (CPU)
 - Up to 20 MHz CPU at 1.8 V to 5.5 V across temperature range of -40°C to 85°C
 - Subset of HC08 instruction set with added BGND instruction
 - Single Global interrupt vector
- On-Chip Memory
 - Up to 12 KB flash read/program/erase over full operating voltage and temperature, 12 KB/8 KB/4 KB/2 KB flash are optional
 - Up to 254-byte random-access memory (RAM), 254-byte/126-byte RAM are optional
 - Security circuitry to prevent unauthorized access to flash contents
- Power-Saving Modes
 - Wait mode — CPU shuts down; system clocks continue to run; full voltage regulation
 - Stop mode — CPU shuts down; system clocks are stopped; voltage regulator in standby
 - Wakeup from power-saving modes using RTI, KBI, ADC, ACMP, SCI and LVD
- Clock Source Options
 - Oscillator (XOSC) — Loop-control Pierce oscillator; crystal or ceramic resonator range of 31.25 kHz to 39.0625 kHz or 1 MHz to 16 MHz
 - Internal Clock Source (ICS) — Internal clock source module containing a frequency-locked-loop (FLL) controlled by internal or external reference; precision trimming of internal reference allows 0.2% resolution and 2% deviation over temperature and voltage; supporting bus frequencies up to 10 MHz
- System Protection
 - Watchdog computer operating properly (COP) reset with option to run from dedicated 1 kHz internal low power oscillator
 - Low-voltage detection with reset or interrupt
 - Illegal opcode detection with reset
 - Illegal address detection with reset
 - Flash-block protection
- Development Support
 - Single-wire background debug interface
 - Breakpoint capability to allow single breakpoint setting during in-circuit debugging
- Peripherals
 - **ADC** — 12-channel, 10-bit resolution; 2.5 μs conversion time; automatic compare function; 1.7 mV/ $^{\circ}\text{C}$ temperature sensor; internal bandgap reference channel; operation in stop; hardware trigger
 - **ACMP** — Analog comparator; full rail-to-rail supply operation; option to compare to fixed internal bandgap reference voltage; can operate in stop mode
 - **TPM** — One 2-channel timer/pulse-width modulator module; selectable input capture, output compare, or buffered edge- or center-aligned PWM on each channel
 - **IIC** — Inter-integrated circuit bus module capable of operation up to 100 kbps with maximum bus loading; capable of higher baud rates with reduced loading
 - **SCI** — One serial communications interface module with optional 13-bit break; LIN extensions
 - **MTIM** — Two 8-bit modulo timers; optional clock sources
 - **RTI** — One real-time clock with optional clock sources
 - **KBI** — Keyboard interrupts; up to 8 ports
- Input/Output
 - 18 GPIOs in 24- and 20-pin packages; 14 GPIOs in 16-pin package; 6 GPIOs in 8-pin package; including one output-only pin and one input-only pin
 - Hysteresis and configurable pullup device on all input pins; configurable slew rate and drive strength on all output pins
- Package Options
 - MC9RS08KB12/MC9RS08KB8/MC9RS08KB4
 - 24-pin QFN, 20-pin SOIC, 16-pin SOIC NB or TSSOP
 - MC9RS08KB2
 - 8-pin SOIC or DFN

This document contains information on a product under development. Freescale reserves the right to change or discontinue this product without notice.

Table 1. Pin Availability by Package Pin-Count

| Pin Number | | | | <-- Lowest Priority --> Highest | | | | |
|------------|----|----|---|---------------------------------|---------------------|---------------------|------------------|-----------------|
| 24 | 20 | 16 | 8 | Port Pin | Alt 1 | Alt 2 | Alt 3 | Alt 4 |
| 1 | 3 | 3 | 3 | | | | | V _{DD} |
| 2 | — | — | — | NC | | | | |
| 3 | 4 | 4 | 4 | | | | | V _{SS} |
| 4 | 5 | 5 | — | PTB7 | SCL ¹ | | | EXTAL |
| 5 | 6 | 6 | — | PTB6 | SDA ¹ | | | XTAL |
| 6 | 7 | 7 | — | PTB5 | TPMCH1 ² | | | |
| 7 | 8 | 8 | — | PTB4 | TPMCH0 ² | | | |
| 8 | 9 | — | — | PTC3 | | | ADP11 | |
| 9 | 10 | — | — | PTC2 | | | ADP10 | |
| 10 | 11 | — | — | PTC1 | | | ADP9 | |
| 11 | 12 | — | — | PTC0 | | | ADP8 | |
| 12 | 13 | 9 | — | PTB3 | KBIP7 | | ADP7 | |
| 13 | 14 | 10 | — | PTB2 | KBIP6 | | ADP6 | |
| 14 | 15 | 11 | — | PTB1 | KBIP5 | TxD ³ | ADP5 | |
| 15 | 16 | 12 | — | PTB0 | KBIP4 | RxD ³ | ADP4 | |
| 16 | 17 | 13 | 5 | PTA3 | KBIP3 | SCL ¹ | TxD ³ | ADP3 |
| 17 | 18 | 14 | 6 | PTA2 | KBIP2 | SDA ¹ | RxD ³ | ADP2 |
| 18 | 19 | 15 | 7 | PTA1 | KBIP1 | TPMCH1 ² | ADP1 | ACMP– |
| 19 | 20 | 16 | 8 | PTA0 | KBIP0 | TPMCH0 ² | ADP0 | ACMP+ |
| 20 | — | — | — | NC | | | | |
| 21 | — | — | — | NC | | | | |
| 22 | — | — | — | NC | | | | |
| 23 | 1 | 1 | 1 | PTA5 | | TCLK | RESET | V _{PP} |
| 24 | 2 | 2 | 2 | PTA4 | ACMPO | BKGD | MS | |

¹ IIC pins can be remapped to PTB6 and PTB7, default reset location is PTA2 and PTA3. It can be configured only once.

² TPM pins can be remapped to PTB4 and PTB5, default reset location is PTA0 and PTA1.

³ SCI pins can be remapped to PTA2 and PTA3, default reset location is PTB0 and PTB1. It can be configured only once.

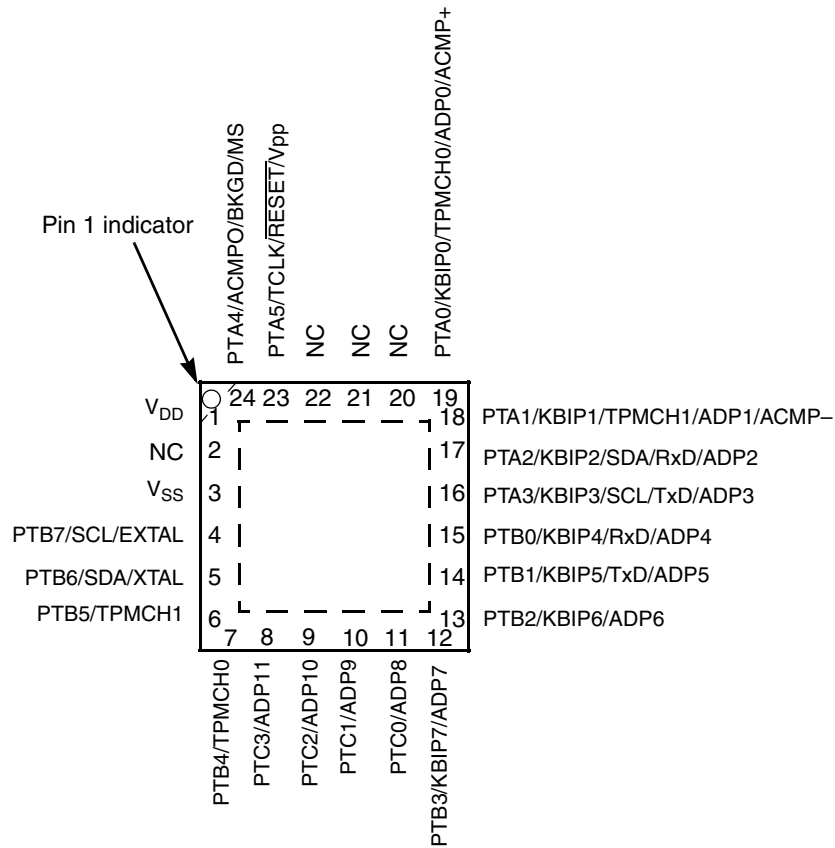


Figure 2. MC9RS08KB12 Series 24-Pin QFN Package

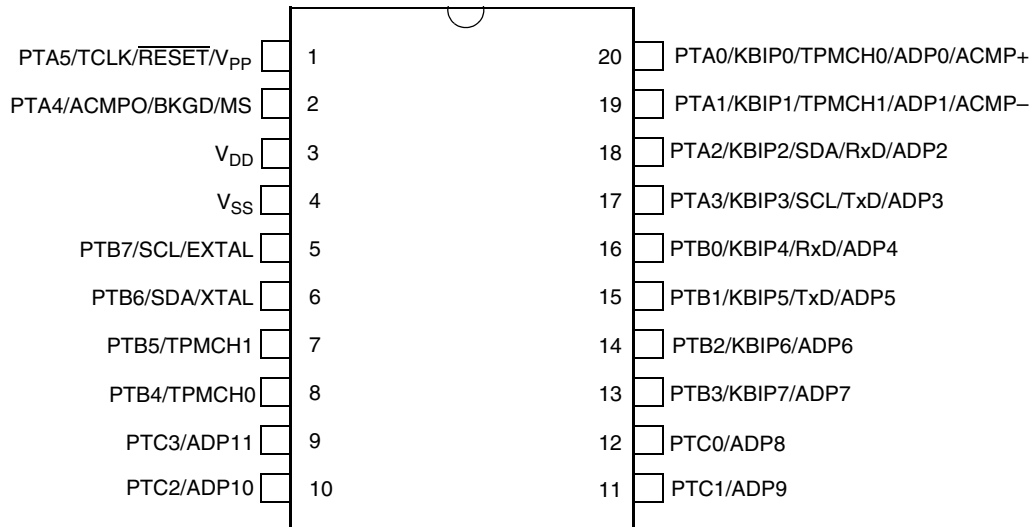


Figure 3. MC9RS08KB12 Series 20-Pin SOIC Package

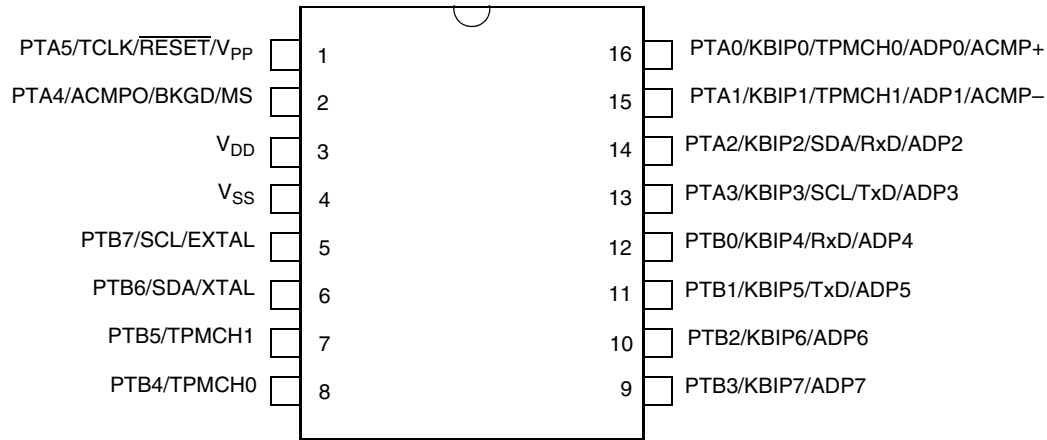


Figure 4. MC9RS08KB12 Series 16-Pin SOIC NB/TSSOP Package

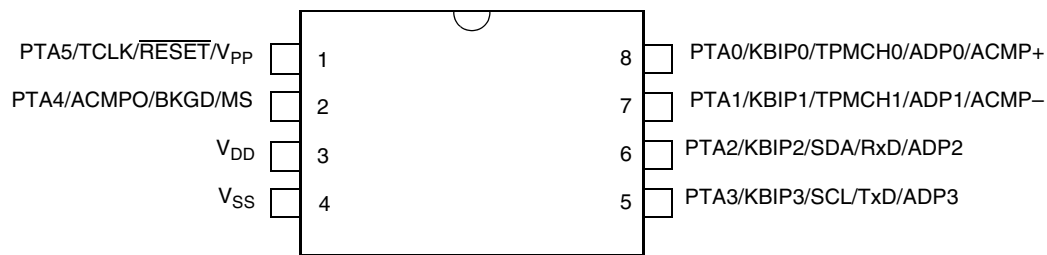


Figure 5. MC9RS08KB12 Series 8-Pin SOIC/DFN Package

3 Electrical Characteristics

3.1 Introduction

This chapter contains electrical and timing specifications for the MC9RS08KB12 series of microcontrollers available at the time of publication.

3.2 Parameter Classification

The electrical parameters shown in this supplement are guaranteed by various methods. To give the customer a better understanding the following classification is used and the parameters are tagged accordingly in the tables where appropriate:

Table 2. Parameter Classifications

| | |
|----------|--|
| P | Those parameters are guaranteed during production testing on each individual device. |
| C | Those parameters are achieved by the design characterization by measuring a statistically relevant sample size across process variations. |
| T | Those parameters are achieved by design characterization on a small sample size from typical devices under typical conditions unless otherwise noted. All values shown in the typical column are within this category. |

Table 2. Parameter Classifications

| | |
|----------|---|
| D | Those parameters are derived mainly from simulations. |
|----------|---|

NOTE

The classification is shown in the column labeled “C” in the parameter tables where appropriate.

3.3 Absolute Maximum Ratings

Absolute maximum ratings are stress ratings only, and functional operation at the maxima is not guaranteed. Stress beyond the limits specified in [Table 3](#) may affect device reliability or cause permanent damage to the device. For functional operating conditions, refer to the remaining tables in this chapter.

This device contains circuitry protecting against damage due to high static voltage or electrical fields; however, it is advised that normal precautions be taken to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (for instance, V_{SS} or V_{DD}) or the programmable pull-up resistor associated with the pin is enabled.

Table 3. Absolute Maximum Ratings

| Rating | Symbol | Value | Unit |
|---|-----------|------------------------|------|
| Supply voltage | V_{DD} | -0.3 to 5.8 | V |
| Maximum current into V_{DD} | I_{DD} | 120 | mA |
| Digital input voltage | V_{In} | -0.3 to $V_{DD} + 0.3$ | V |
| Instantaneous maximum current Single pin limit (applies to all port pins) ^{1, 2, 3} | I_D | ±25 | mA |
| Storage temperature range | T_{stg} | -55 to 150 | °C |

¹ Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive (V_{DD}) and negative (V_{SS}) clamp voltages, then use the larger of the two resistance values.

² All functional non-supply pins are internally clamped to V_{SS} and V_{DD} except the \overline{RESET}/V_{PP} pin which is internally clamped to V_{SS} only.

³ Power supply must maintain regulation within operating V_{DD} range during instantaneous and operating maximum current conditions. If positive injection current ($V_{In} > V_{DD}$) is greater than I_{DD} , the injection current may flow out of V_{DD} and could result in external power supply going out of regulation. Ensure external V_{DD} load will shunt current greater than maximum injection current. This will be the greatest risk when the MCU is not consuming power. Examples are: if no system clock is present, or if the clock rate is very low which would reduce overall power consumption.

3.4 Thermal Characteristics

This section provides information about operating temperature range, power dissipation, and package thermal resistance. Power dissipation on I/O pins is usually small compared to the power dissipation in on-chip logic and voltage regulator circuits and it is user-determined rather than being controlled by the MCU design. In order to take $P_{I/O}$ into account in power calculations, determine the difference between actual pin voltage and V_{SS} or V_{DD} and multiply by the pin current for each I/O pin. Except in cases of

Electrical Characteristics

unusually high pin current (heavy loads), the difference between pin voltage and V_{SS} or V_{DD} will be very small.

Table 4. Thermal Characteristics

| Rating | Symbol | Value | Unit |
|--|---------------|-----------------------------|------|
| Operating temperature range (packaged) | T_A | T_L to T_H -40 to 85 | °C |
| Maximum junction temperature | T_{JMAX} | 150 | °C |
| Thermal resistance 24-pin QFN | θ_{JA} | 113 | °C/W |
| Thermal resistance 20-pin SOIC | θ_{JA} | 83 | °C/W |
| Thermal resistance 16-pin SOIC NB | θ_{JA} | 103 | °C/W |
| Thermal resistance 16-pin TSSOP | θ_{JA} | 29 | °C/W |
| Thermal resistance 8-pin SOIC | θ_{JA} | 150 | °C/W |
| Thermal resistance 8-pin DFN | θ_{JA} | 110 | °C/W |

The average chip-junction temperature (T_J) in °C can be obtained from:

$$T_J = T_A + (P_D \times \theta_{JA}) \quad \text{Eqn. 1}$$

where:

T_A = Ambient temperature, °C

θ_{JA} = Package thermal resistance, junction-to-ambient, °C /W

$P_D = P_{int} + P_{I/O}$

$P_{int} = I_{DD} \times V_{DD}$, Watts chip internal power

$P_{I/O}$ = Power dissipation on input and output pins user determined

For most applications, $P_{I/O} \ll P_{int}$ and can be neglected. An approximate relationship between P_D and T_J (if $P_{I/O}$ is neglected) is:

$$P_D = K \div (T_J + 273^\circ\text{C}) \quad \text{Eqn. 2}$$

Solving [Equation 1](#) and [Equation 2](#) for K gives:

$$K = P_D \times (T_A + 273^\circ\text{C}) + \theta_{JA} \times (P_D)^2 \quad \text{Eqn. 3}$$

where K is a constant pertaining to the particular part. K can be determined from [Equation 3](#) by measuring P_D (at equilibrium) for a known T_A . Using this value of K, the values of P_D and T_J can be obtained by solving [Equation 1](#) and [Equation 2](#) iteratively for any value of T_A .

3.5 ESD Protection and Latch-Up Immunity

Although damage from electrostatic discharge (ESD) is much less common on these devices than on early CMOS circuits, normal handling precautions must be used to avoid exposure to static discharge.

Qualification tests are performed to ensure that these devices can withstand exposure to reasonable levels of static without suffering any permanent damage.

During the device qualification ESD stresses were performed for the human body model (HBM) and the charge device model (CDM).

A device is defined as a failure if after exposure to ESD pulses the device no longer meets the device specification. Complete DC parametric and functional testing is performed per the applicable device specification at room temperature followed by hot temperature, unless specified otherwise in the device specification.

Table 5. ESD and Latch-Up Test Conditions

| Model | Description | Symbol | Value | Unit |
|--------------|-----------------------------|---------------|--------------|-------------|
| Human body | Series resistance | R1 | 1500 | Ω |
| | Storage capacitance | C | 100 | pF |
| | Number of pulses per pin | — | 1 | — |
| Latch-up | Minimum input voltage limit | — | -2.5 | V |
| | Maximum input voltage limit | — | 7.5 | V |

Table 6. ESD and Latch-Up Protection Characteristics

| No. | Rating ¹ | Symbol | Min | Max | Unit |
|-----|--|-----------|-------|-----|------|
| 1 | Human body model (HBM) | V_{HBM} | ±2000 | — | V |
| 2 | Charge device model (CDM) | V_{CDM} | ±500 | — | V |
| 3 | Latch-up current at $T_A = 85\text{ °C}$ | I_{LAT} | ±100 | — | mA |

¹ Parameter is achieved by design characterization on a small sample size from typical devices under typical conditions unless otherwise noted.

3.6 DC Characteristics

This section includes information about power supply requirements, I/O pin characteristics, and power supply current in various operating modes.

Table 7. DC Characteristics (Temperature Range = –40 to 85°C Ambient)

| No. | C | Parameter | Symbol | Min | Typical | Max | Unit |
|-----|---|---|-------------|----------------------|----------------|----------------------|------|
| 1 | — | Supply voltage (run, wait and stop modes.) $0 < f_{BUS} < 10\text{ MHz}$ | V_{DD} | 1.8 | — | 5.5 | V |
| 2 | C | Minimum RAM retention supply voltage applied to V_{DD} | V_{RAM} | 0.8 ¹ | — | — | V |
| 3 | P | Low-voltage detection threshold (V_{DD} falling) (V_{DD} rising) | V_{LVD} | 1.80 1.88 | 1.86 1.94 | 1.95 2.05 | V |
| 4 | C | Power on RESET (POR) voltage | V_{POR}^1 | 0.9 | — | 1.7 | V |
| 5 | C | Input high voltage ($V_{DD} > 2.3\text{V}$) (all digital inputs) | V_{IH} | $0.70 \times V_{DD}$ | — | — | V |
| 6 | C | Input high voltage ($1.8\text{ V} \leq V_{DD} \leq 2.3\text{ V}$) (all digital inputs) | V_{IH} | $0.85 \times V_{DD}$ | — | — | V |
| 7 | C | Input low voltage ($V_{DD} > 2.3\text{ V}$) (all digital inputs) | V_{IL} | — | — | $0.30 \times V_{DD}$ | V |
| 8 | C | Input low voltage ($1.8\text{ V} \leq V_{DD} \leq 2.3\text{ V}$) (all digital inputs) | V_{IL} | — | — | $0.30 \times V_{DD}$ | V |
| 9 | C | Input hysteresis (all digital inputs) | V_{hys}^1 | $0.06 \times V_{DD}$ | — | — | V |
| 10 | P | Input leakage current (per pin) $V_{In} = V_{DD}$ or V_{SS} , all input only pins | I_{InI} | — | 0.025 | 1.0 | μA |
| 11 | P | High impedance (off-state) leakage current (per pin) $V_{In} = V_{DD}$ or V_{SS} , all input/output | I_{IOZ} | — | 0.025 | 1.0 | μA |
| 12 | P | Internal pullup resistors ² (all port pins) | R_{PU} | 20 | 45 | 65 | kΩ |
| 13 | P | Internal pulldown resistors ² (all port pins) | R_{PD} | 20 | 45 | 65 | kΩ |
| 14 | C | Output high voltage — Low drive (PTxDSn = 0) 5 V, $I_{Load} = 2\text{ mA}$ 3 V, $I_{Load} = 1\text{ mA}$ 1.8 V, $I_{Load} = 0.5\text{ mA}$ | V_{OH} | $V_{DD} - 0.8$ | — | — | V |
| | | Output high voltage — High drive (PTxDSn = 1) 5 V, $I_{Load} = 5\text{ mA}$ 3 V, $I_{Load} = 3\text{ mA}$ 1.8 V, $I_{Load} = 2\text{ mA}$ | | | $V_{DD} - 0.8$ | — | |
| 15 | C | Maximum total IOH for all port pins | $ I_{OHT} $ | — | — | 40 | mA |

Table 7. DC Characteristics (Temperature Range = -40 to 85°C Ambient) (continued)

| No. | C | Parameter | Symbol | Min | Typical | Max | Unit |
|-----|---|---|-----------|-----|---------|-----|------|
| 16 | C | Output low voltage — Low drive (PTxDSn = 0) 5 V, $I_{Load} = 2$ mA 3 V, $I_{Load} = 1$ mA 1.8 V, $I_{Load} = 0.5$ mA | V_{OL} | — | — | 0.8 | V |
| | | Output low voltage — High drive (PTxDSn = 1) 5 V, $I_{Load} = 5$ mA 3 V, $I_{Load} = 3$ mA 1.8 V, $I_{Load} = 2$ mA | | — | — | | |
| 17 | C | Maximum total IOI for all port pins | I_{OLT} | — | — | 40 | mA |
| 18 | C | DC injection current ^{3, 4, 5, 6} $V_{In} < V_{SS}$, $V_{In} > V_{DD}$ Single pin limit | | — | — | 0.2 | mA |
| | | Total MCU limit, includes sum of all stressed pins | | — | — | 0.8 | |
| 19 | C | Input capacitance (all non-supply pins) | C_{In} | — | — | 7 | pF |

¹ This parameter is characterized and not tested on each device.

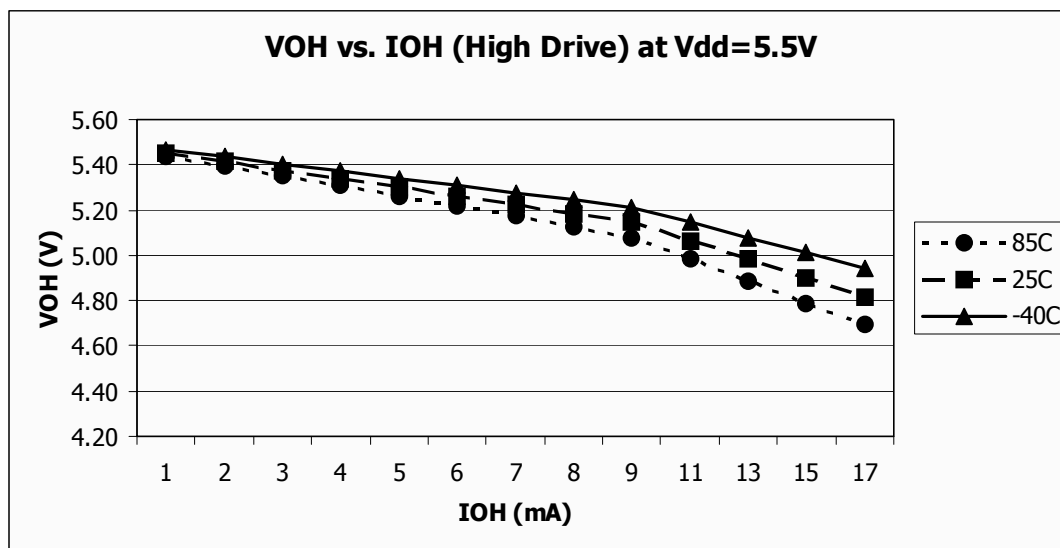
² Measurement condition for pull resistors: $V_{In} = V_{SS}$ for pullup and $V_{In} = V_{DD}$ for pulldown.

³ All functional non-supply pins are internally clamped to V_{SS} and V_{DD} except the \overline{RESET}/V_{PP} which is internally clamped to V_{SS} only.

⁴ Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive and negative clamp voltages, then use the larger of the two values.

⁵ Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive and negative clamp voltages, then use the larger of the two values.

⁶ This parameter is characterized and not tested on each device.



**Figure 6. Typical V_{OH} vs. I_{OH}
 $V_{DD} = 5.5$ V (High Drive)**

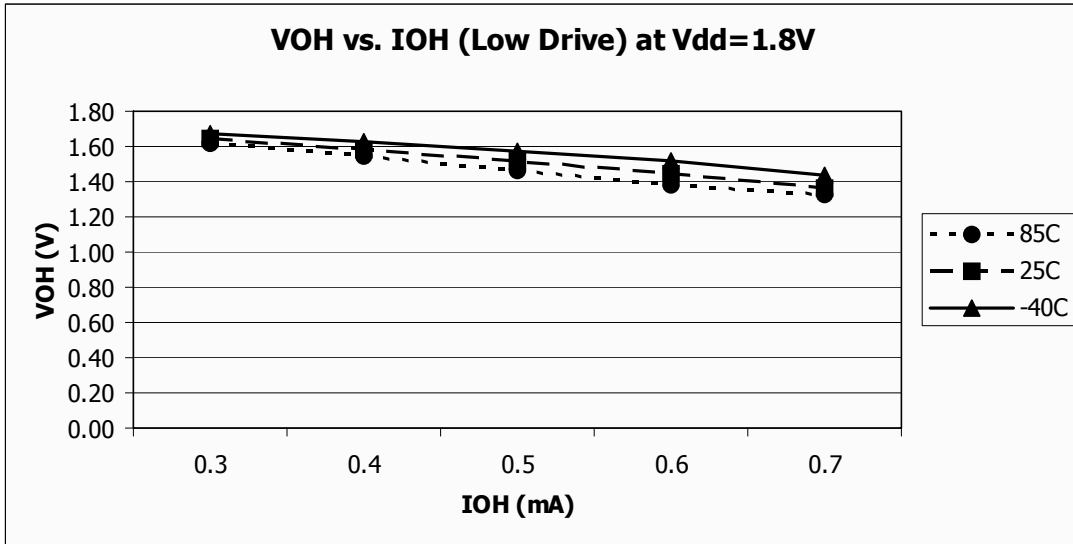


Figure 11. Typical V_{OH} vs. I_{OH}
 $V_{DD} = 1.8\text{ V}$ (Low Drive)

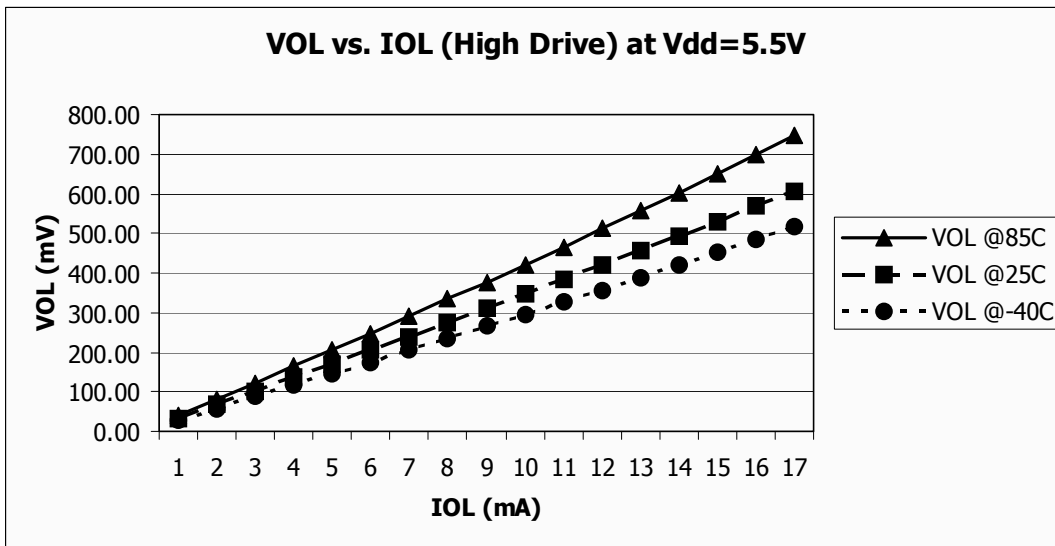


Figure 12. Typical V_{OL} vs. I_{OL}
 $V_{DD} = 5.5\text{ V}$ (High Drive)

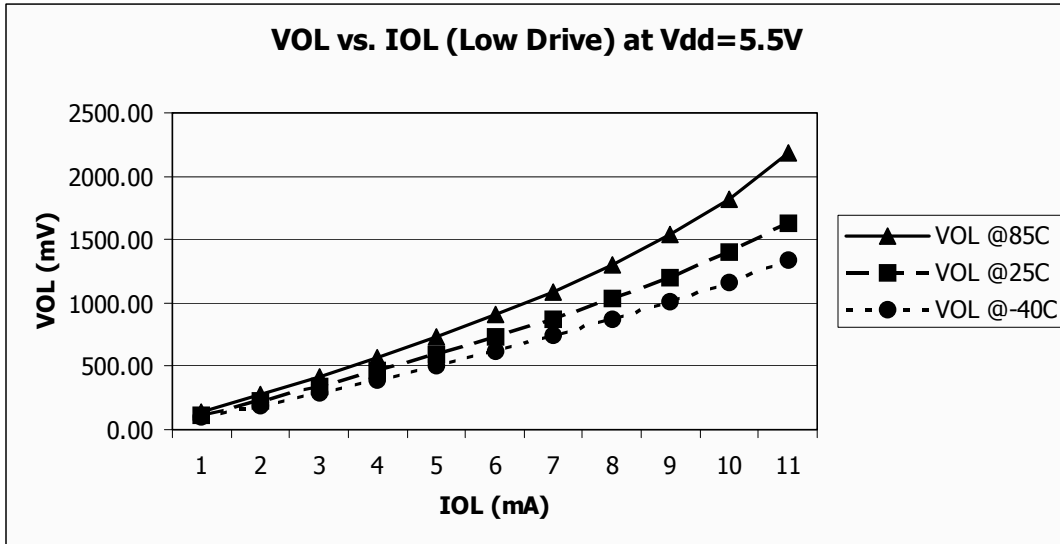


Figure 13. Typical V_{OL} vs. I_{OL}
 $V_{DD} = 5.5 V$ (Low Drive)

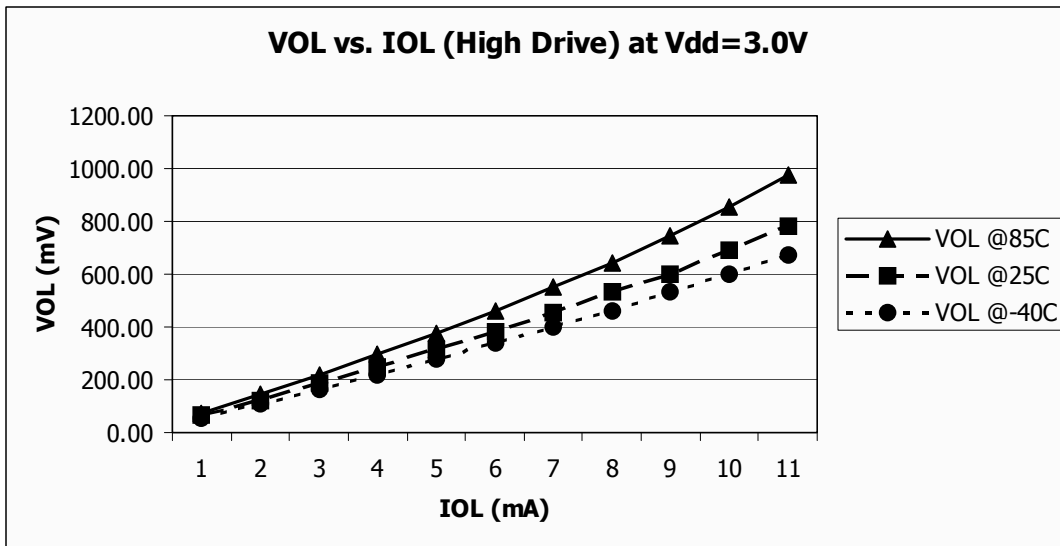


Figure 14. Typical V_{OL} vs. I_{OL}
 $V_{DD} = 3.0 V$ (High Drive)

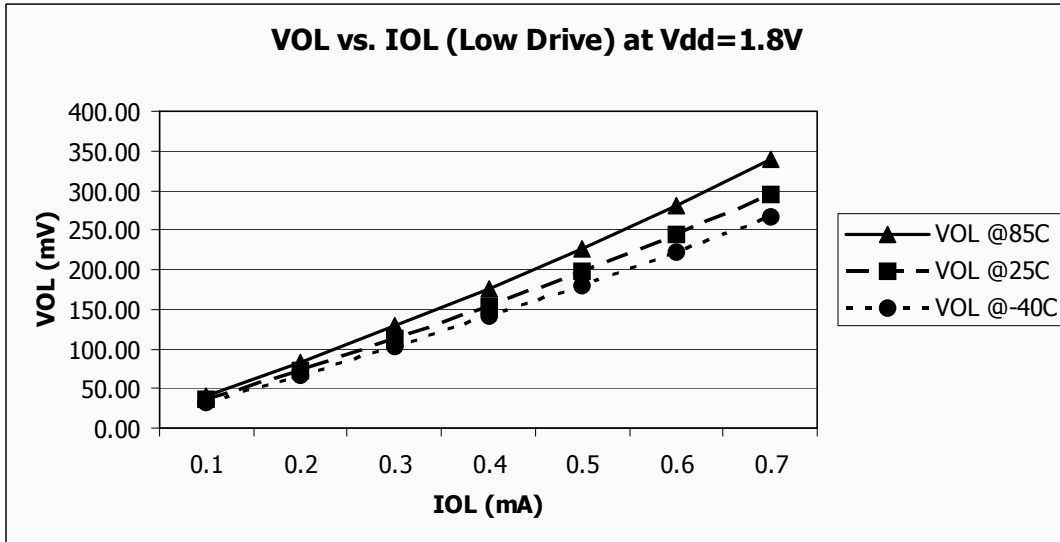


Figure 17. Typical V_{OL} vs. I_{OL}
 $V_{DD} = 1.8\text{ V}$ (Low Drive)

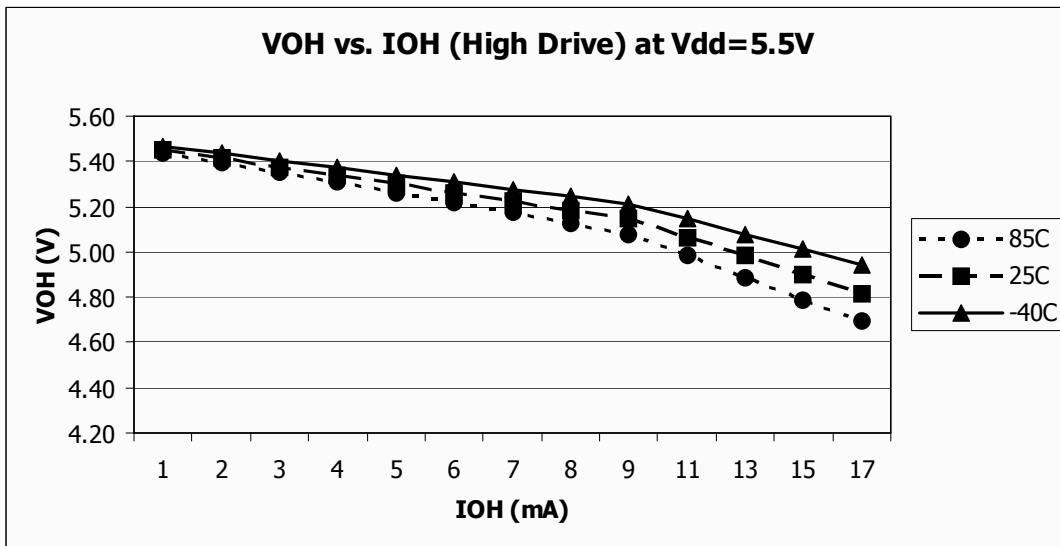


Figure 18. Typical I_{OH} vs. $V_{DD}-V_{OH}$
 $V_{DD} = 5.5\text{ V}$ (High Drive)

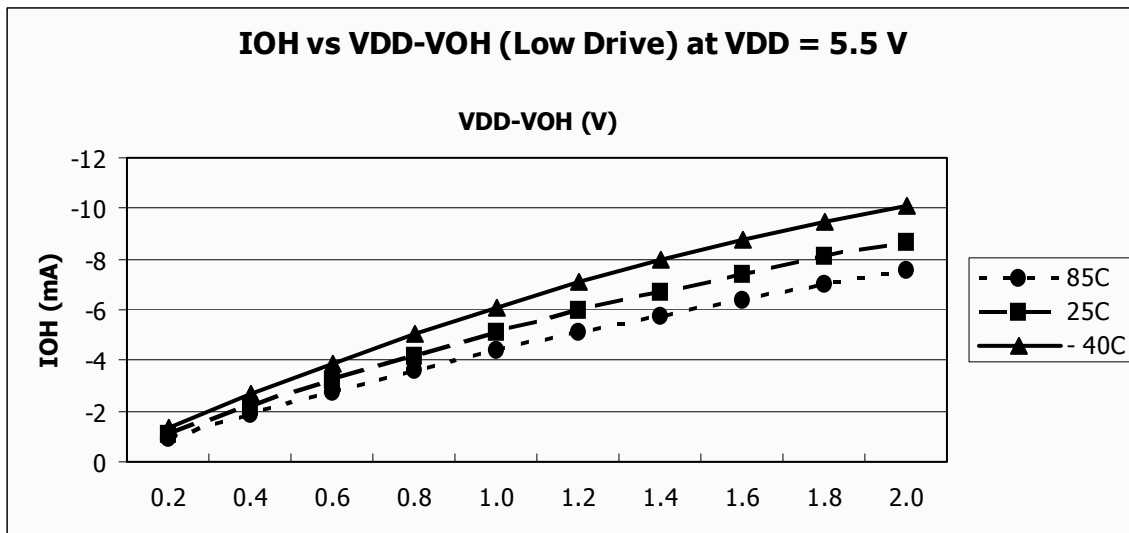


Figure 19. Typical I_{OH} vs. V_{DD}-V_{OH}
V_{DD} = 5.5 V (Low Drive)

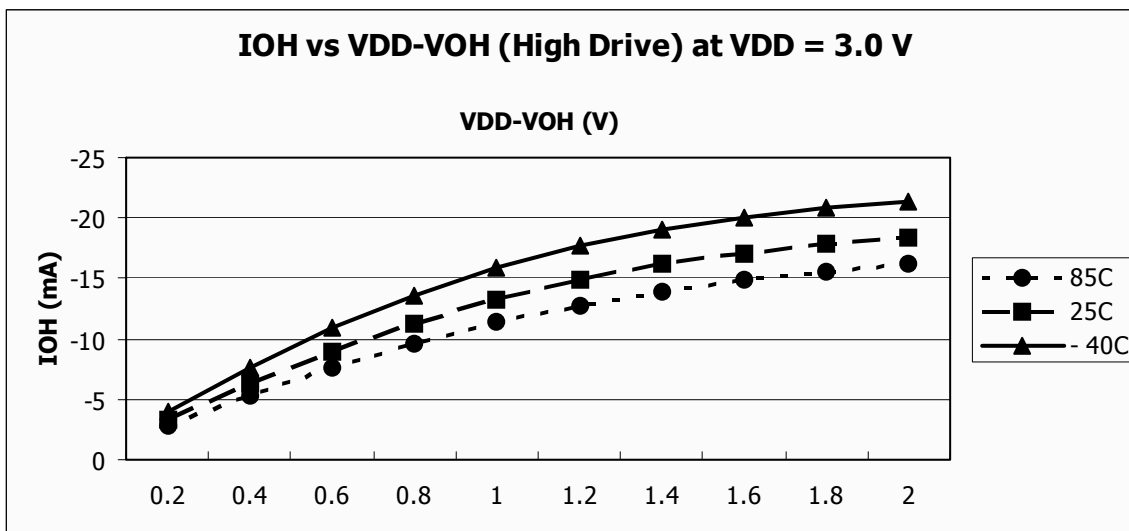


Figure 20. Typical I_{OH} vs. V_{DD}-V_{OH}
V_{DD} = 3 V (High Drive)

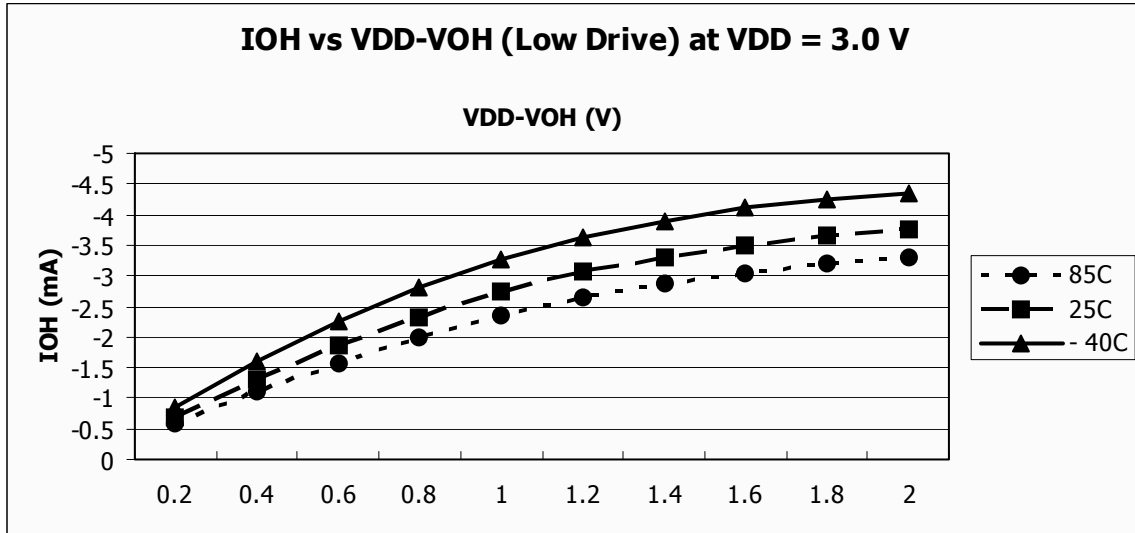


Figure 21. Typical I_{OH} vs. $V_{DD}-V_{OH}$
 $V_{DD} = 3\text{ V}$ (Low Drive)

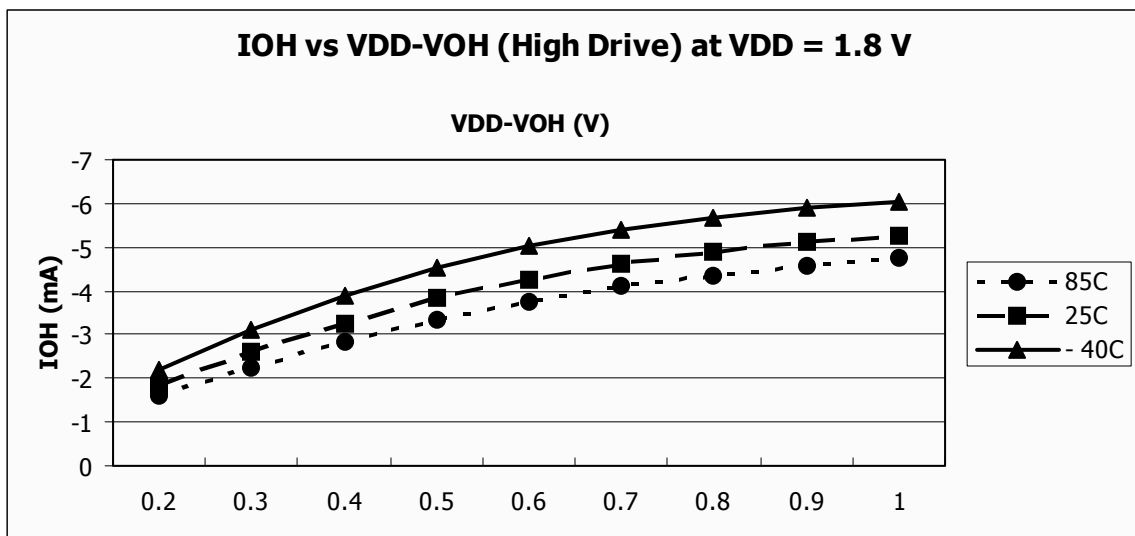


Figure 22. Typical I_{OH} vs. $V_{DD}-V_{OH}$
 $V_{DD} = 1.8\text{ V}$ (High Drive)

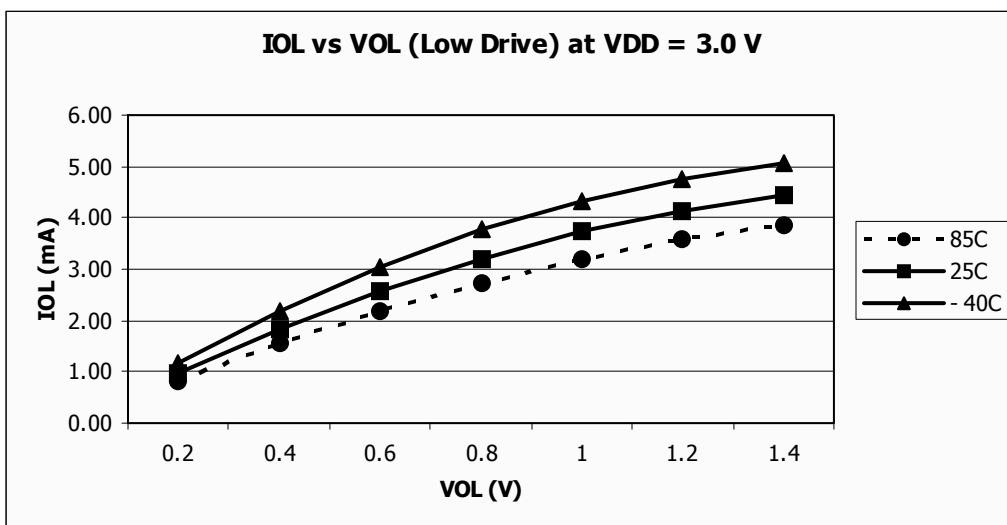


Figure 27. Typical I_{OL} vs. V_{OL}
 $V_{DD} = 3\text{ V}$ (Low Drive)

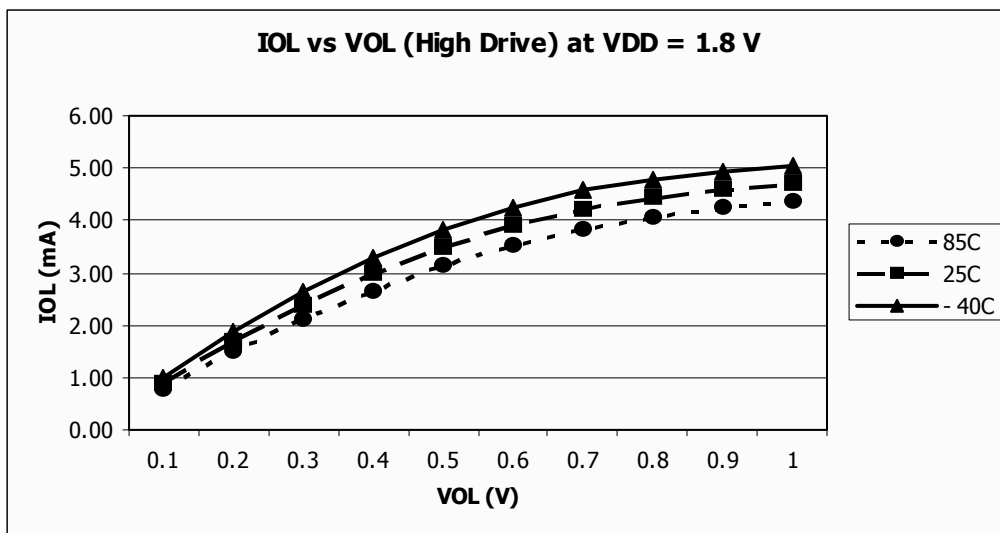


Figure 28. Typical I_{OL} vs. V_{OL}
 $V_{DD} = 1.8\text{ V}$ (High Drive)

Table 8. Supply Current Characteristics (continued)

| N | C | Parameter | Symbol | V _{DD} (V) | Typical | Max ¹ | Temp. (°C) | Unit |
|----|---|---|--------------------|---------------------|----------------------------|------------------|-----------------|------|
| 7 | C | Wait mode supply current ³ measured at (f _{Bus} = 2.00 MHz) | W _I DD2 | 5 | 841.13 859.98 873.69 | — | –40 25 85 | μA |
| 8 | T | | | 3 | 840.21 850.60 846.67 | — | –40 25 85 | |
| 9 | T | | | 1.80 | 630.64 635.10 643.67 | — | –40 25 85 | |
| 10 | C | Wait mode supply current ³ measured at (f _{Bus} = 1.00 MHz) | W _I DD1 | 5 | 667.86 683.38 688.02 | — | –40 25 85 | μA |
| 11 | T | | | 3 | 666.34 672.79 669.15 | — | –40 25 85 | |
| 12 | T | | | 1.80 | 505.39 509.28 502.52 | — | –40 25 85 | |
| 13 | P | Stop mode supply current | S _I DD | 5 | 1.15 1.40 7.67 | 11 | –40 25 85 | μA |
| 14 | C | | | 3 | 1.05 1.26 4.52 | — | –40 25 85 | |
| 15 | C | | | 1.80 | 0.39 0.56 4.21 | — | –40 25 85 | |
| 16 | C | ADC adder from stop ³ | — | 5 | 128.86 140.44 154.97 | — | –40 25 85 | μA |
| 17 | T | | | 3 | 102.98 111.71 118.33 | — | –40 25 85 | |
| 18 | T | | | 1.80 | 54.77 66.33 74.42 | — | –40 25 85 | |
| 19 | C | ACMP adder from stop (ACME = 1) | — | 5 | 14.43 15.96 16.77 | — | –40 25 85 | μA |
| 20 | T | | | 3 | 14.37 14.72 14.45 | — | –40 25 85 | |
| 21 | T | | | 1.80 | 13.05 14.02 12.92 | — | –40 25 85 | |

3.8 External Oscillator (XOSC) Characteristics

Table 9. Oscillator Electrical Specifications (Temperature Range = -40 to 85°C Ambient)

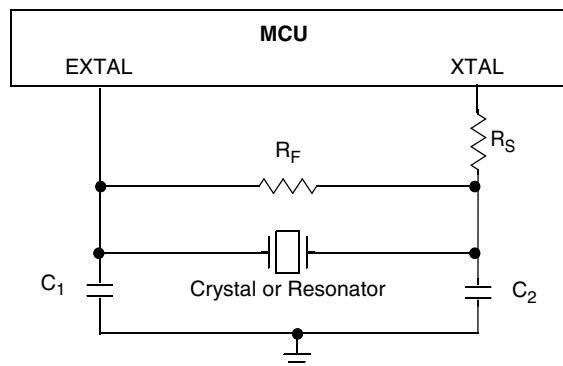
| Num | C | Rating | Symbol | Min | Typical ¹ | Max | Unit |
|-----|---|--|----------------|---|----------------------|------|------|
| 1 | C | Oscillator crystal or resonator (EREFS = 1, ERCLKEN = 1) | | | | | |
| | | Low range (RANGE = 0) | f_{lo} | 32 | — | 38.4 | kHz |
| | | High range (RANGE = 1) FEE or FBE mode ² | f_{hi} | 1 | — | 5 | MHz |
| | | High range (RANGE = 1, HGO = 1) FBELP mode | f_{hi-hgo} | 1 | — | 16 | MHz |
| | | High range (RANGE = 1, HGO = 0) FBELP mode | f_{hi-lp} | 1 | — | 8 | MHz |
| 2 | D | Load capacitors | C_1, C_2 | See crystal or resonator manufacturer's recommendation. | | | |
| 3 | D | Feedback resistor | R_F | | | | |
| | | Low range (32 kHz to 100 kHz) | | — | 10 | — | MΩ |
| | | High range (1 MHz to 16 MHz) | | — | 1 | — | |
| 4 | D | Series resistor | R_S | | | | |
| | | Low range, low gain (RANGE = 0, HGO = 0) | | — | 0 | — | |
| | | Low range, high gain (RANGE = 0, HGO = 1) | | — | 100 | — | |
| | | High range, low gain (RANGE = 1, HGO = 0) | | — | 0 | — | kΩ |
| | | High range, high gain (RANGE = 1, HGO = 1) | | | | | |
| | | ≥ 8 MHz | — | 0 | 0 | | |
| | | 4 MHz | — | 0 | 10 | | |
| | | 1 MHz | — | 0 | 20 | | |
| 5 | C | Crystal start-up time ³ | | | | | |
| | | Low range, low gain (RANGE = 0, HGO = 0) | $t_{CSTL-LP}$ | — | 200 | — | ms |
| | | Low range, high gain (RANGE = 0, HGO = 1) | $t_{CSTL-HGO}$ | — | 400 | — | |
| | | High range, low gain (RANGE = 1, HGO = 0) ⁴ | $t_{CSTH-LP}$ | — | 5 | — | |
| | | High range, high gain (RANGE = 1, HGO = 1) ⁴ | $t_{CSTH-HGO}$ | — | 20 | — | |
| 6 | D | Square wave input clock frequency (EREFS = 0, ERCLKEN = 1) | | | | | |
| | | FEE or FBE mode ² | f_{extal} | 0.03125 | — | 5 | MHz |
| | | FBELP mode | | 0 | — | 40 | |

¹ Typical data was characterized at 5.0 V, 25 °C or is recommended value.

² The input clock source must be divided using RDIV to within the range of 31.25 kHz to 39.0625 kHz.

³ This parameter is characterized and not tested on each device. Proper PC board layout procedures must be followed to achieve specifications.

⁴ 4 MHz crystal.



3.9 AC Characteristics

This section describes AC timing characteristics for each peripheral system.

Table 15. 10-Bit ADC Characteristics ($V_{REFH} = V_{DDAD}$, $V_{REFL} = V_{SSAD}$, $2.7\text{ V} < V_{DDAD} < 5.5\text{ V}$)

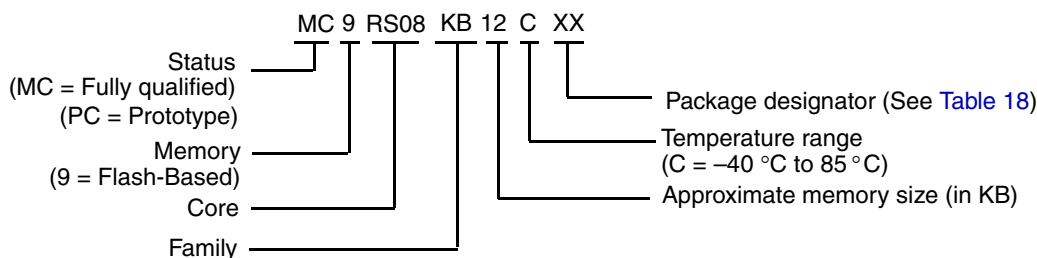
| C | Characteristic | Conditions | Symb | Min | Typ ¹ | Max | Unit | Comment |
|--|---|---------------------------|-------------|------|------------------|-----------|------------------|--|
| C | Supply Current ADLPC = 0 ADLSMP = 0 ADCO = 1 | | I_{DDAD} | — | 0.582 | 1 | mA | |
| C | ADC Asynchronous Clock Source | High Speed (ADLPC = 0) | f_{ADACK} | 2 | 3.3 | 5 | MHz | $t_{ADACK} = 1/f_{ADACK}$ |
| | | Low Power (ADLPC = 1) | | 1.25 | 2 | 3.3 | | |
| D | Conversion Time (Including sample time) | Short Sample (ADLSMP = 0) | t_{ADC} | — | 20 | — | ADCK cycles | See reference manual for conversion time variances |
| | | Long Sample (ADLSMP = 1) | | — | 40 | — | | |
| D | Sample Time | Short Sample (ADLSMP = 0) | t_{ADS} | — | 3.5 | — | ADCK cycles | |
| | | Long Sample (ADLSMP = 1) | | — | 23.5 | — | | |
| C | Total Unadjusted Error | 10-bit mode | E_{TUE} | — | ± 1.5 | ± 3.5 | LSB ² | Includes quantization |
| | | 8-bit mode | | — | ± 0.7 | ± 1.5 | | |
| T | Differential Non-Linearity | 10-bit mode | DNL | — | ± 0.5 | ± 1.0 | LSB ² | |
| | | 8-bit mode | | — | ± 0.3 | ± 0.5 | | |
| Monotonicity and No-Missing-Codes guaranteed | | | | | | | | |
| C | Integral Non-Linearity | 10-bit mode | INL | — | ± 0.5 | ± 1.0 | LSB ² | |
| | | 8-bit mode | | — | ± 0.3 | ± 0.5 | | |
| P | Zero-Scale Error | 10-bit mode | E_{ZS} | — | ± 1.5 | ± 2.5 | LSB ² | $V_{ADIN} = V_{SSA}$ |
| | | 8-bit mode | | — | ± 0.5 | ± 0.7 | | |
| P | Full-Scale Error | 10-bit mode | E_{FS} | — | ± 1 | ± 1.5 | LSB ² | $V_{ADIN} = V_{DDA}$ |
| | | 8-bit mode | | — | ± 0.5 | ± 0.5 | | |
| D | Quantization Error | 10-bit mode | E_Q | — | — | ± 0.5 | LSB ² | |
| | | 8-bit mode | | — | — | ± 0.5 | | |
| D | Input Leakage Error | 10-bit mode | E_{IL} | — | ± 0.2 | ± 2.5 | LSB ² | Pad leakage ^{2*} R_{AS} |
| | | 8-bit mode | | — | ± 0.1 | ± 1 | | |

¹ Typical values assume $V_{DDAD} = 5.0\text{ V}$, $\text{Temp} = 25\text{ }^\circ\text{C}$, $f_{ADCK} = 1.0\text{ MHz}$ unless otherwise stated. Typical values are for reference only and are not tested in production.

² Based on input pad leakage current. Refer to pad electricals.

4 Ordering Information

This section contains ordering numbers for MC9RS08KB12 series devices. See below for an example of the device numbering system.



5 Package Information and Mechanical Drawings

Table 18 provides the available package types and their document numbers. The latest package outline/mechanical drawings are available on the MC9RS08KB12 Series Product Summary pages at <http://www.freescale.com>.

To view the latest drawing, either:

- Click on the appropriate link in Table 18, or
- Open a browser to the Freescale® website (<http://www.freescale.com>), and enter the appropriate document number (from Table 18) in the “Enter Keyword” search box at the top of the page.

Table 18. Device Numbering System

| Device Number | Memory | | Package | | |
|--|--------|-----------|------------|------------|-----------------------------|
| | Flash | RAM | Type | Designator | Document No. |
| MC9RS08KB12 MC9RS08KB8 MC9RS08KB4 | 12 KB | 254 bytes | 24 QFN | FK | 98ASA00087D |
| | 8 KB | 254 bytes | 20 SOIC WB | WJ | 98ASB42343B |
| | 4 KB | 126 bytes | 16 SOIC NB | SG | 98ASB42566B |
| | | | 16 TSSOP | TG | 98ASH70247A |
| MC9RS08KB2 | 2 KB | 126 bytes | 8 SOIC NB | SC | 98ASB42564B |
| | | | 8 DFN | DC | 98ARL10557D |

How to Reach Us:

Home Page:

www.freescale.com

Web Support:

<http://www.freescale.com/support>

USA/Europe or Locations Not Listed:

Freescale Semiconductor, Inc.
Technical Information Center, EL516
2100 East Elliot Road
Tempe, Arizona 85284
1-800-521-6274 or +1-480-768-2130
www.freescale.com/support

Europe, Middle East, and Africa:

Freescale Halbleiter Deutschland GmbH
Technical Information Center
Schatzbogen 7
81829 Muenchen, Germany
+44 1296 380 456 (English)
+46 8 52200080 (English)
+49 89 92103 559 (German)
+33 1 69 35 48 48 (French)
www.freescale.com/support

Japan:

Freescale Semiconductor Japan Ltd.
Headquarters
ARCO Tower 15F
1-8-1, Shimo-Meguro, Meguro-ku,
Tokyo 153-0064
Japan
0120 191014 or +81 3 5437 9125
support.japan@freescale.com

Asia/Pacific:

Freescale Semiconductor China Ltd.
Exchange Building 23F
No. 118 Jianguo Road
Chaoyang District
Beijing 100022
China
+86 10 5879 8000
support.asia@freescale.com

For Literature Requests Only:

Freescale Semiconductor Literature Distribution Center
P.O. Box 5405
Denver, Colorado 80217
1-800-441-2447 or +1-303-675-2140
Fax: +1-303-675-2150
LDCForFreescaleSemiconductor@hibbertgroup.com

Information in this document is provided solely to enable system and software implementers to use Freescale Semiconductor products. There are no express or implied copyright licenses granted hereunder to design or fabricate any integrated circuits or integrated circuits based on the information in this document.

Freescale Semiconductor reserves the right to make changes without further notice to any products herein. Freescale Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Freescale Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters that may be provided in Freescale Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals", must be validated for each customer application by customer's technical experts. Freescale Semiconductor does not convey any license under its patent rights nor the rights of others. Freescale Semiconductor products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Freescale Semiconductor product could create a situation where personal injury or death may occur. Should Buyer purchase or use Freescale Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold Freescale Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Freescale Semiconductor was negligent regarding the design or manufacture of the part.

RoHS-compliant and/or Pb-free versions of Freescale products have the functionality and electrical characteristics as their non-RoHS-compliant and/or non-Pb-free counterparts. For further information, see <http://www.freescale.com> or contact your Freescale sales representative.

For information on Freescale's Environmental Products program, go to <http://www.freescale.com/epp>.

Freescale™ and the Freescale logo are trademarks of Freescale Semiconductor, Inc. All other product or service names are the property of their respective owners.

© Freescale Semiconductor, Inc. 2008-2012. All rights reserved.

Document Number: MC9RS08KB12

Rev. 5

1/2012